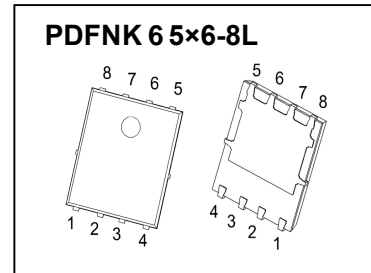




CJAC110SN10 N-Channel Power MOSFET

V_{(BR)DSS}	R_{DS(on)}TYP	I_D
100V	4.3mΩ@10V	110A



DESCRIPTION

The CJAC110SN10 uses shielded gate trench technology and design to provide excellent R_{DS(ON)} with low gate charge. It can be used in a wide variety of applications

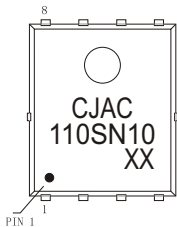
FEATURES

- High Power and current handing capability
- Load switch
- High density cell design for ultra low R_{DS(ON)}
- Lead free product is acquired
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

APPLICATIONS

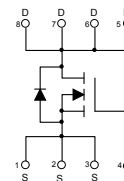
- SMPS and general purpose applications
- Hard switched and high frequency circuits
- Uninterruptible Power Supply
- Power management

MARKING



CJAC110SN10 = Part No.
 Solid dot = Pin1 indicator
 XX = Code

EQUIVALENT CIRCUIT



ABSOLUTE MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _{GS}	±20	
Continuous Drain Current	I _D ^①	110	A
Pulsed Drain Current	I _{DM} ^②	390	
Maximum Power Dissipation	P _D ^⑥	192	W
Single Pulsed Avalanche Energy	E _{AS} ^③	320	mJ
Thermal Resistance from Junction to Case	R _{θJC} ^①	0.65	°C/W
Thermal Resistance from Junction to Ambient	R _{θJA} ^⑥	62.5	°C/W
Junction Temperature	T _J	150	°C
Storage Temperature	T _{STG}	-55~ +150	
Lead Temperature for Soldering Purposes(1/8" from case for 10s)	T _L	260	

MOSFET ELECTRICAL CHARACTERISTICS

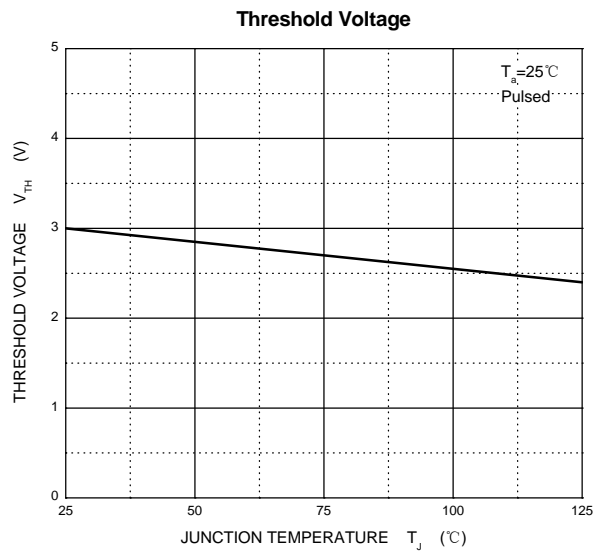
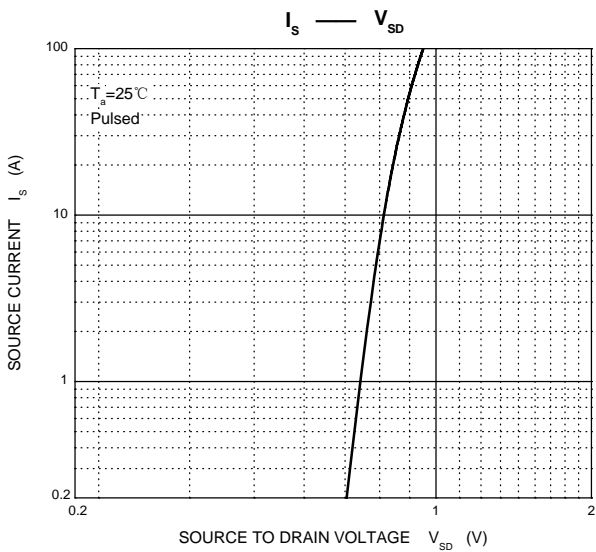
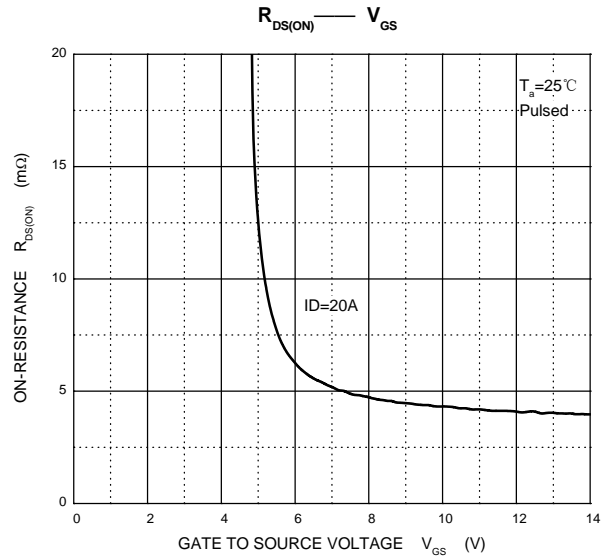
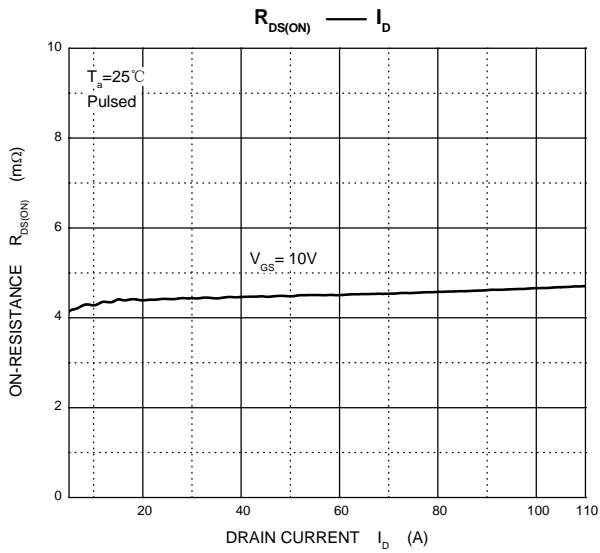
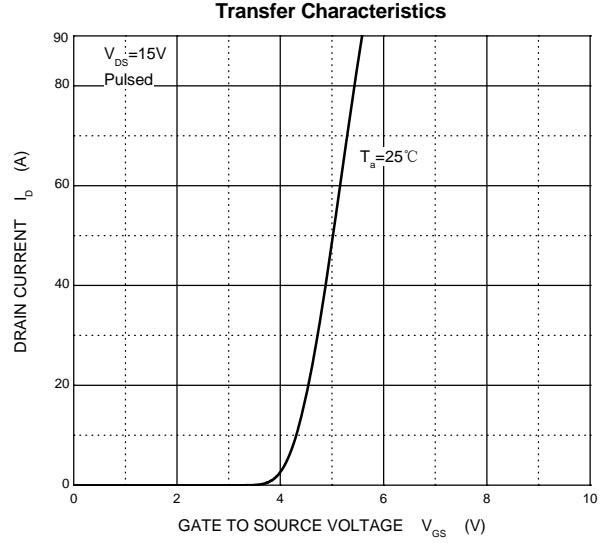
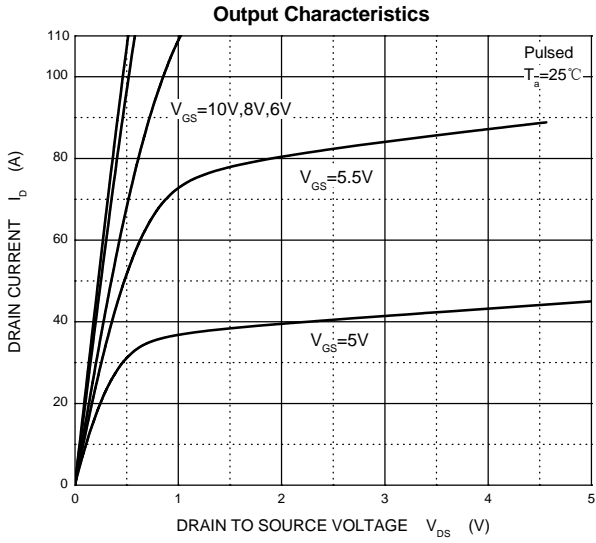
$T_a=25\text{ }^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	100			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 80V, V_{GS} = 0V$			1	μA
Gate-body leakage current	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 20V$			± 100	nA
On characteristics ^④						
Gate-threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	2.0	3.0	4.0	V
Static drain-source on-state resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 20A$		4.3	5.0	m Ω
Dynamic characteristics ^{④ ⑤}						
Input capacitance	C_{iss}	$V_{DS} = 45V, V_{GS} = 0V,$ $f = 100KHz$		3907	7500	pF
Output capacitance	C_{oss}			794	1600	
Reverse transfer capacitance	C_{rss}			16	32	
Gate resistance	R_g	$f = 1MHz$		1.9		Ω
Switching characteristics ^{④ ⑤}						
Total gate charge	Q_g	$V_{GS} = 10V, V_{DS} = 50V,$ $I_D = 22A$		66.5	140	nC
Gate-source charge	Q_{gs}			15.9	33	
Gate-drain charge	Q_{gd}			19.8	40	
Turn-on delay time	$t_{d(on)}$	$V_{DS} = 50V, I_D = 22A,$ $V_{GS} = 10V, R_G = 2.2\Omega$		28	60	ns
Turn-on rise time	t_r			7.5	15	
Turn-off delay time	$t_{d(off)}$			82	164	
Turn-off fall time	t_f			20	40	
Drain-Source Diode Characteristics						
Drain-source diode forward voltage	V_{SD} ^④	$V_{GS} = 0V, I_S = 25A$			1.0	V
Continuous drain-source diode forward current	I_S ^①				110	A
Pulsed drain-source diode forward current	I_{SM} ^②				390	A

Notes:

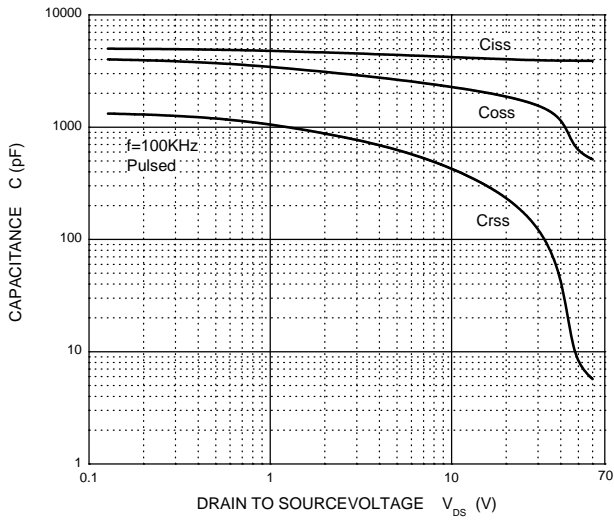
- V_{OMG} $^\circ\text{C}$ Limited only by maximum temperature allowed.
- $P_{W} \leq 10\mu s$, Duty cycle $\leq 1\%$.
- EAS condition: $V_{DD} = 30V, V_{GS} = 10V, L = 0.5mH, R_g = 25\Omega$ Starting $T_J = 25^\circ\text{C}$.
- Pulse Test : Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
- Guaranteed by design, not subject to production.
- The value of $R_{\theta JA}$ is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with $T_a = 25^\circ\text{C}$.

Typical Characteristics

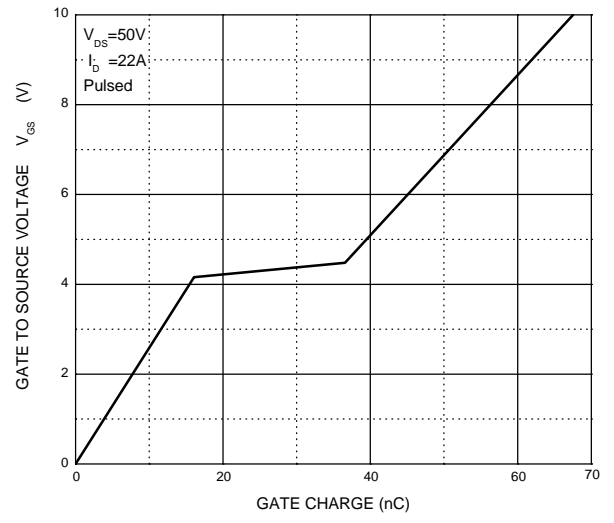


Typical Characteristics

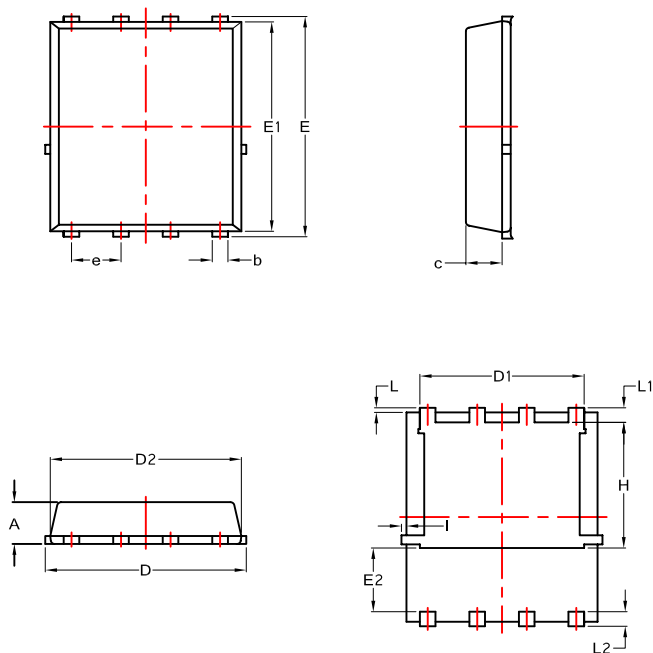
Capacitances



Gate Charge

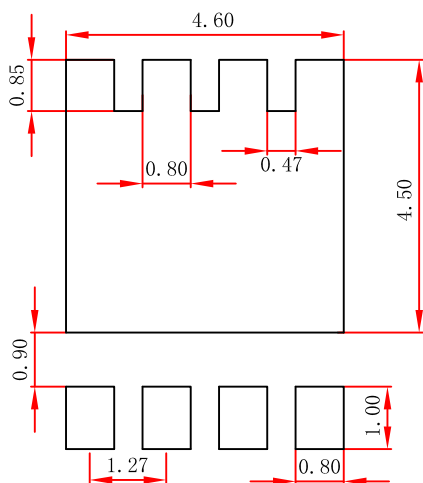


PDFNWB5x6-8L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.03	1.17	0.0406	0.0461
b	0.34	0.48	0.0134	0.0189
c	0.824	0.970	0.0324	0.0382
D	4.80	5.40	0.1890	0.2126
D1	4.11	4.31	0.1618	0.1697
D2	4.80	5.00	0.1890	0.1969
E	5.95	6.15	0.2343	0.2421
E1	5.65	5.85	0.2224	0.2303
E2	1.60	-	0.0630	-
e	1.270 BSC	-	0.050 BSC	-
L	0.05	0.25	0.0020	0.0098
L1	0.38	0.50	0.0150	0.0197
L2	0.38	0.50	0.0150	0.0197
H	3.30	3.50	0.1299	0.1378
I	-	0.18	-	0.0070

PDFNWB5x6-8L Suggested Pad Layout



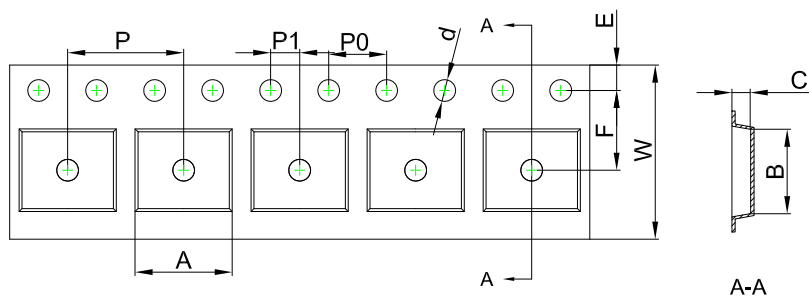
- Note:
1. Controlling dimension: in millimeters.
 2. General tolerance: ± 0.05 mm.
 3. The pad layout is for reference purposes only.

NOTICE

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PDFNWB5×6 Tape and Reel

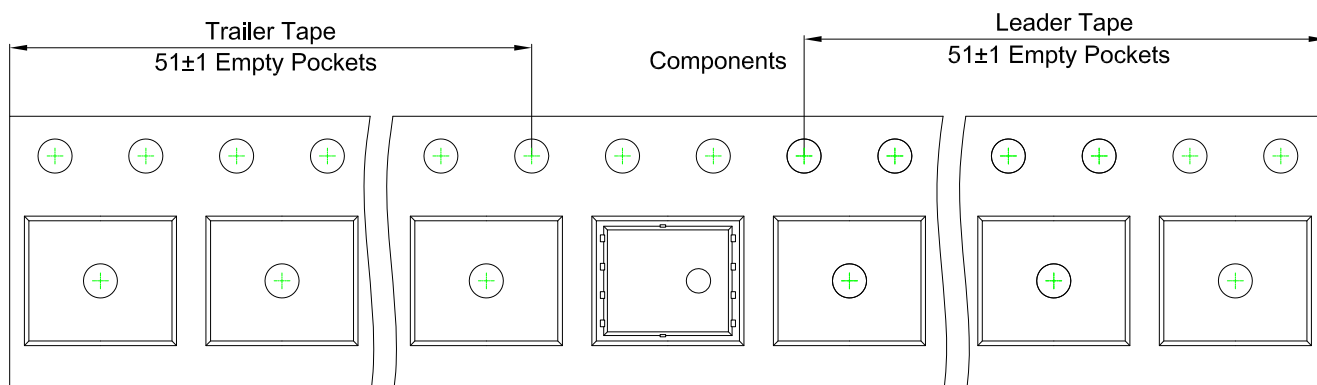
PDFNWB5×6-8L Embossed Carrier Tape



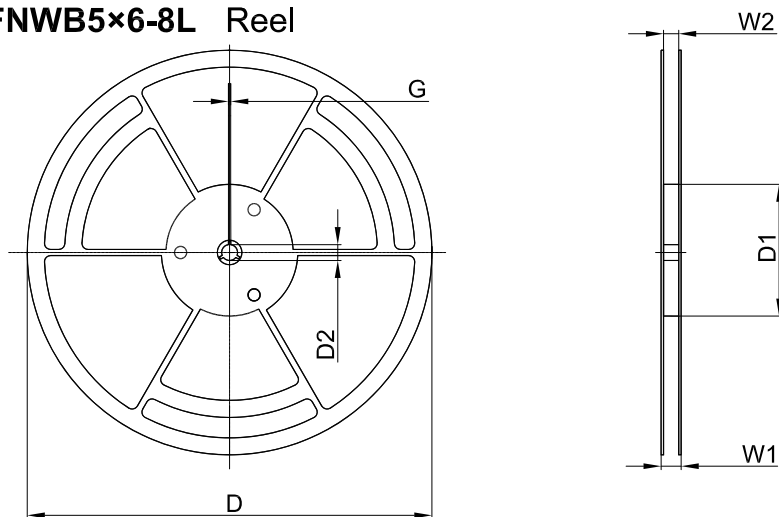
Packaging Description:
PDFNWB5×6-8L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 5,000 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
PDFNWB5×6-8L	6.30	5.30	1.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

PDFNWB5×6-8L Tape Leader and Trailer



PDFNWB5×6-8L Reel



Dimensions are in millimeter						
Reel Option	D	D1	D2	G	W1	W2
13"Dia	Ø330.00	100.00	13.00	1.90	17.60	12.40

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)
5,000 pcs	13 inch	5,000 pcs	340×336×29	50,000 pcs	353×346×365

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